

W005M THRU W10M

Silicon Bridge Rectifiers

Reverse Voltage : 50 - 1000 V

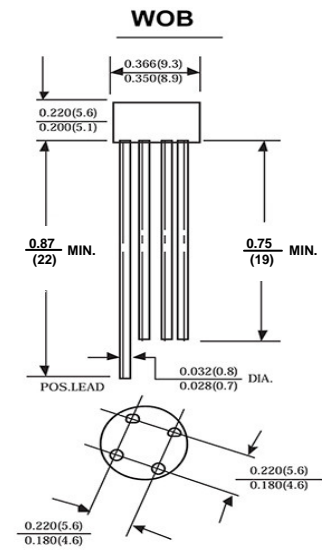
Forward Current : 1.5 A

Features

- Rating to 1000 V PRV
- Ideal for printed circuit board
- Reliable low cost construction utilizing molded plastic technique results in inexpensive product
- Glass passivated chip junction

Mechanical Data

- **Case:** WOB, Molded plastic
- **Polarity:** As marked on Body



Dimensions in inches and (millimeters)

Absolute Maximum Ratings and Characteristics

Ratings at $T_a = 25^\circ\text{C}$ ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Parameter	Symbols	W005M	W01M	W02M	W04M	W06M	W08M	W10M	Units
	Marking	W005M	W01M	W02M	W04M	W06M	W08M	W10M	-
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	V_{RMS}	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V_{DC}	50	100	200	400	600	800	1000	V
Maximum Average Forward Output Current at $T_C = 50^\circ\text{C}$	$I_{F(AV)}$	1.5							A
Peak Forward Surge Current, 8.3 ms Single Half-Sine-Wave Superimposed on Rated Load (JEDEC Method)	I_{FSM}	50							A
Maximum Instantaneous Forward Voltage at 1 A	V_F	1							V
Maximum Reverse Current $T_a = 25^\circ\text{C}$ at Rated DC Blocking Voltage $T_a = 125^\circ\text{C}$	I_R	5 0.5							μA mA
Operating Junction Temperature Range	T_j	- 55 to + 125							$^\circ\text{C}$
Storage Temperature Range	T_{stg}	- 55 to + 150							$^\circ\text{C}$

